NXP BT136X-600D 4Q Triac datasheet

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Planar passivated very sensitive gate four quadrant triac in a SOT186A "full pack" plastic package intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants. This very sensitive gate "series D" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

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1. General description

Planar passivated very sensitive gate four quadrant triac in a SOT186A "full pack" plastic package intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants. This very sensitive gate "series D" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- Direct triggering from low power drivers and logic ICs
- High blocking voltage capability
- Isolated package
- Low holding current for small load currents and lowest EMI at commutation
- Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Very sensitive gate

3. Applications

- General purpose motor control
- General purpose switching

4. Quick reference data

•

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|--|---|-----|-----|-----|------|
| V _{DRM} | repetitive peak off- state voltage | | - | - | 600 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u> | - | - | 25 | A |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_h \le 92$ °C; Fig. 1; Fig. 2; Fig. 3 | - | - | 4 | A |
| Static char | acteristics | · · · · · · | | | | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$ | - | 2 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _i = 25 °C; <u>Fig. 7</u> | - | 2.5 | 5 | mA |





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| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|----------------|-----------------|--|-----|-----|-----|------|
| | | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 7 | - | 2.5 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 10 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 1.2 | 10 | mA |

5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-------------------------|---|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | T2 |
| 2 | T2 | main terminal 2 | | sym051 |
| 3 | G | gate | | - June - |
| mb | n.c. | mounting base; isolated | () () () () () () () () () () () () () (| |

6. Ordering information

| Table 3. Ordering in | formation | | |
|----------------------|-----------|---|---------|
| Type number | Package | | |
| | Name | Description | Version |
| BT136X-600D | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack" | SOT186A |

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7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-----|-----|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_h \le 92$ °C; Fig. 1; Fig. 2; Fig. 3 | - | 4 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$ | - | 25 | A |
| | | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$ | - | 27 | A |
| l ² t | I ² t for fusing | t _p = 10 ms; SIN | - | 3.1 | A ² s |
| dI _T /dt | rate of rise of on-state current | I_T = 6 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2+ G+ | - | 50 | A/µs |
| | | I_T = 6 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2+ G- | - | 50 | A/µs |
| | | I _T = 6 A; I _G = 0.2 A; dI _G /dt = 0.2 A/μs; T2- G- | - | 50 | A/µs |
| | | I _T = 6 A; I _G = 0.2 A; dI _G /dt = 0.2 A/μs; T2- G+ | - | 10 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |

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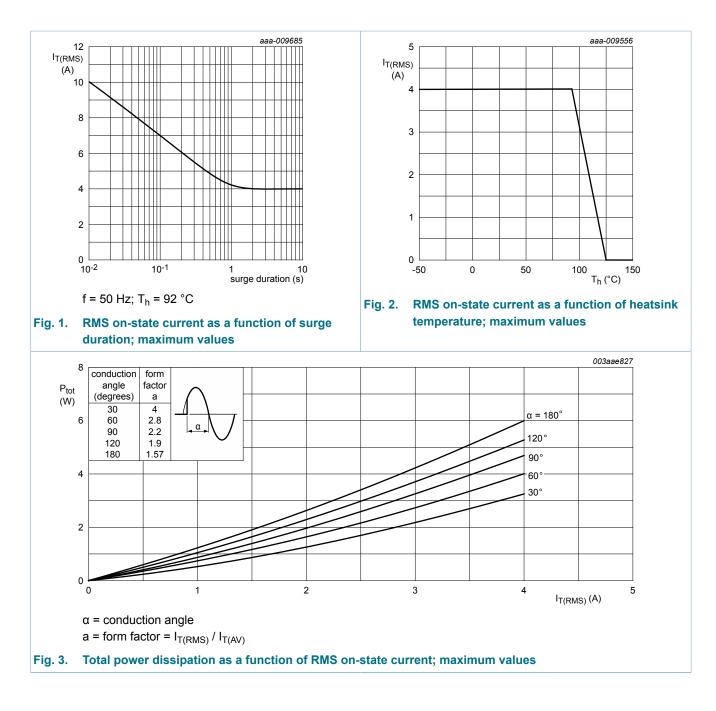
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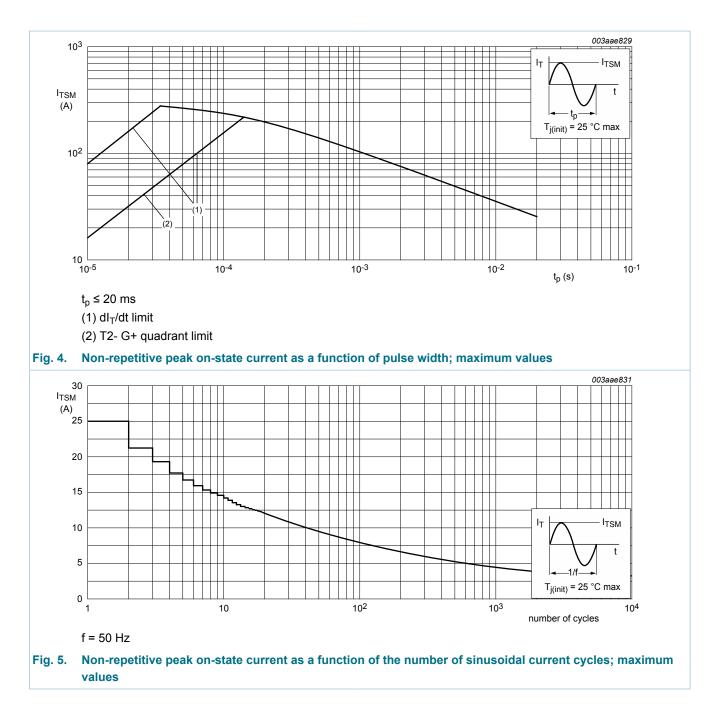
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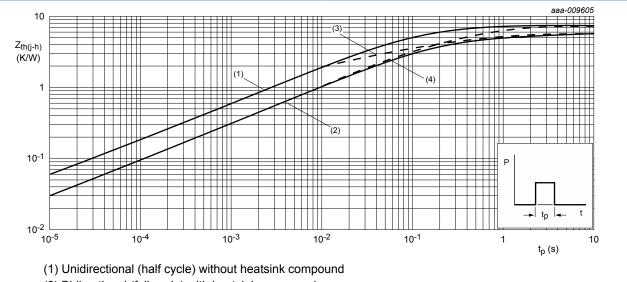
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8. Thermal characteristics

| Table 5. Th | nermal characteristics | | | | | |
|----------------------|---|---|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-h)} | thermal resistance from junction to | full or half cycle; with heatsink compound; Fig. 6 | - | - | 5.5 | K/W |
| | heatsink | full or half cycle; without heatsink compound; Fig. 6 | - | - | 7.2 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 55 | - | K/W |



(2) Bidirectional (full cycle) with heatsink compound

- (3) Unidirectional (half cycle) with heatsink compound
- (4) Bidirectional (full cycle) without heatsink compound

Fig. 6. Transient thermal impedance from junction to heatsink as a function of pulse width

9. Isolation characteristics

| Table 6. Iso | lation characteristics | | | | | |
|------------------------|------------------------|--|-----|-----|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
| V _{isol(RMS)} | RMS isolation voltage | from all terminals to external heatsink; sinusoidal waveform; clean and dust free ; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C | - | - | 2500 | V |
| C _{isol} | isolation capacitance | from main terminal 2 to external heatsink ; f = 1 MHz; T _h = 25 °C | - | 10 | - | pF |

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| | | |

10. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|---------------------|-----------------------------------|--|-------|-----|-----|------|
| Static chara | acteristics | 1 | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 2 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 2.5 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 2.5 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 10 | mA |
| IL | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | 1.6 | 10 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | 1.2 | 15 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u> | - | 2.2 | 10 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 8</u> | - | 1.2 | 15 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 1.2 | 10 | mA |
| V _T | on-state voltage | I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.4 | 1.7 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic ch | aracteristics | · | · · · | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | - | 5 | - | V/µs |
| t _{gt} | gate-controlled turn-on time | I_{TM} = 6 A; V _D = 600 V; I _G = 0.1 A; dI _G / dt = 5 A/µs | - | 2 | - | μs |

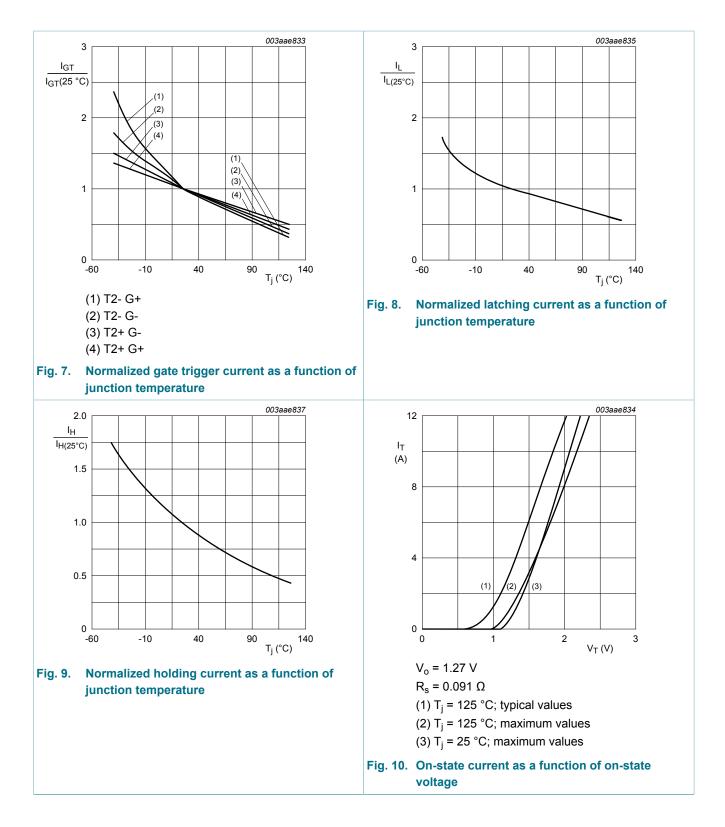
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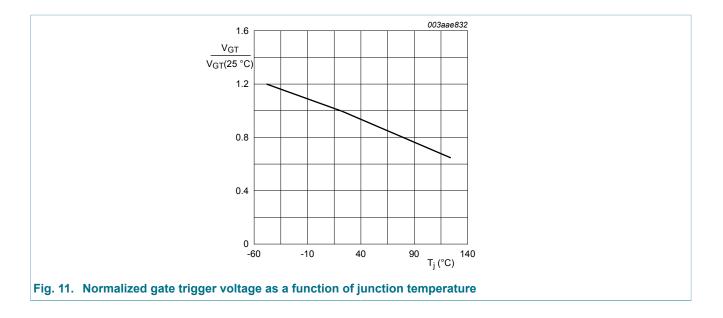
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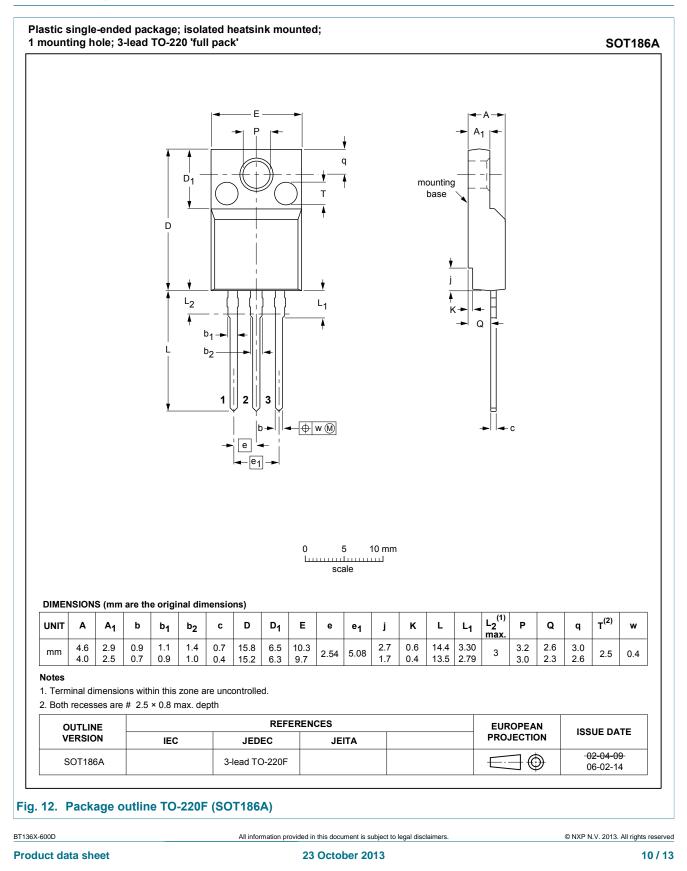
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11. Package outline



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12. Legal information

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